

US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	1/6/2006 9:30
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IS&R	S1	2 ("6700096").PN.
BRS	S2	1 puls\$3 and S1
BRS	S3	1 puls\$3 and continuous and S1
IS&R	S4	10 (("20040069751") or ("20040169023") or ("20040171237") or ("20040253838") or ("20040259387")).PN.
BRS	S5	5 puls\$3 and continuous and S4
IS&R	L3	4 ("6700096") or ("6242292")).PN.
BRS	L4	46898 puls\$3 and continuous and overlap\$4
BRS	L5	3533 (puls\$3 near7 laser) and (continuous near7 laser) and overlap\$4
BRS	L6	2322 crystal\$8 and 5
BRS	L7	1807 semiconductor\$4 and 6
BRS	L8	476 438/\$.ccls. and 7
BRS	L9	196 yamazaki.in. and 8
BRS	L10	82 ((puls\$3 near7 laser) and (continuous near7 laser) and overlap\$4).clm.
BRS	L11	6 yamazaki.in. and 10